

S9014 NPN Transistors

General description

SOT-23 Plastic-Encapsulate Transistors

SOT-23

FEATURES

Complementary to S9015

- Power Dissipation of 200mW
- High Stability and High Reliability

1. BASE 2. EMITTER 3. COLLECTOR



MECHANICAL DATA

SOT-23 Small Outline Plastic Package

- Epoxy UL: 94V-0
- Mounting Position: Any

Marking: J6

Maximum Ratings & Thermal Characteristics T_A = 25°C unless otherwise noted

Parameters	Symbol	Value	Unit
Collector-Base Voltage	Vсво	50	V
Collector-Emitter Voltage	VCEO	45	V
Emitter -Base Voltage	VEBO	5	V
Collector Current-Continuous	Ic	100	mA
Collector Power Dissipation	Pc	200	mW
Junction Temperature	Tj	150	$^{\circ}$
Storage Temperature	Tstg	-55-+150	$^{\circ}$
Thermal resistance From junction to ambient	Reja	625	°C/W

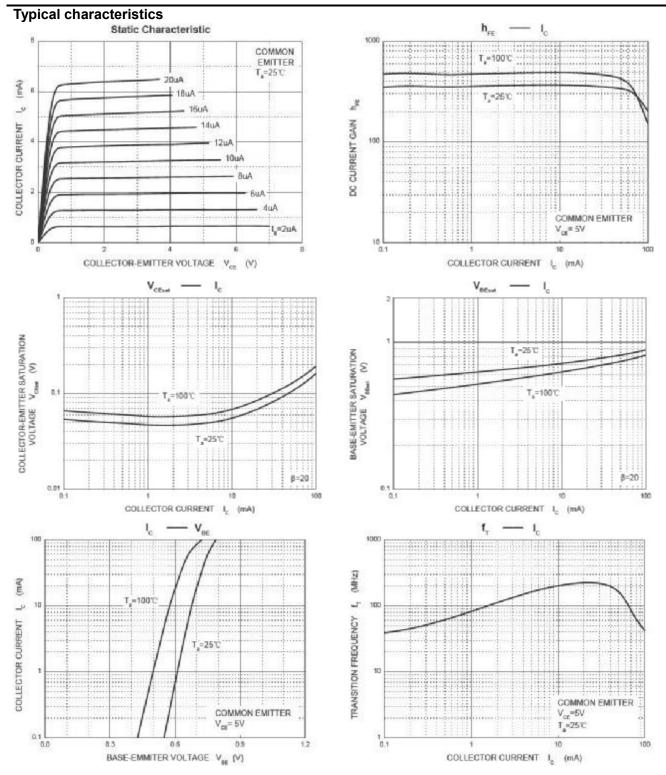
Electrical Characteristics T_A = 25°C unless otherwise noted

Parameter	Symbols Test Condition		Limits		Unit
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Collector-base breakdown voltage	V(BR)CBO	IC=100uA, IE=0	50		V
Collector-emitter breakdown voltage	V(BR)CEO	IC=0.1mA, IB=0	45		V
Emitter-base breakdown voltage	V(BR)EBO	IE=100uA, IC=0	5		٧
Collector cut-off current	ICEO	VCE=20V, IB=0		100	nA
Collector cut-off current	Ісво	VCB=40V, IE=0		100	nA
Emitter cut-off current	IEBO	VEB=5V, IC=0		100	nA
DC current gain	hFE(1)	VCE=1V, IC=100mA	200	1000	
	hFE(2)	VCE=1V, IC=800mA		0.30	
Collector-emitter saturation voltage	VCE(sat)	IC=800mA, IB=80mA		1.00	V
Base -emitter saturation voltage	VBE(sat)	IC=800mA, IB=80mA	150		V
Transition frequency	fT	VCE=10V, IC=50mA,f=30MHz	50		MHz

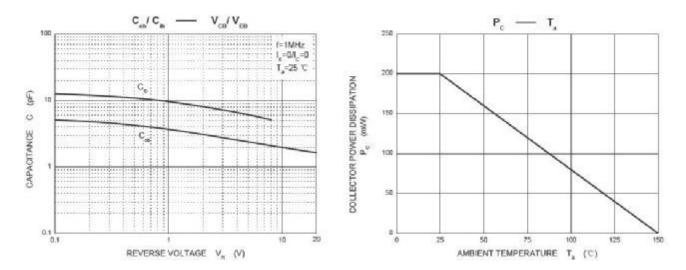
CLASSIFICATION OF hfe(1)

RANK	L	Н
RANGE	200-450	450-1000

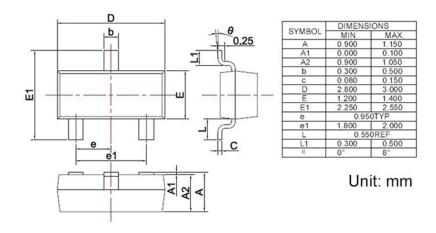




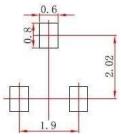




SOT-23 PACKAGE OUTLINE Plastic surface mounted package



Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.



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